

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2452	(ge germanium)near11 (impurit\$3 low\$4 trace\$2)	US-PGPUB	OR	ON	2005/11/11 17:06
L2	464	(ge germanium)near11 (("10" "1" "5" "3" "4" "6" "7" "8" "9") adj2 (percent "%"))	US-PGPUB	OR	ON	2005/11/11 17:07
L3	171653	(amorphous adj1 silicon ".alpha.si" a-si polysilicon polycrystalline microcrystalline silicon)	US-PGPUB	OR	ON	2005/11/11 17:07
L4	207575	((("101" "{101}" "{101}" "[101]" "101")("001" "{001}" "{001}" "[001]" "001")("111" "{111}" "{111}" "[111]" "111") near21 (lattice plane orient\$6))	US-PGPUB	OR	ON	2005/11/11 17:07
L5	839	((amorphous adj1 silicon ".alpha.si" "a-si" polysilicon polycrystalline \$6crystalline silicon)near32 (lattice plane orient\$6))same (diffraction)	US-PGPUB	OR	ON	2005/11/11 17:08
L6	698	1 and 3 and 4	US-PGPUB	OR	ON	2005/11/11 16:51
L7	37	1 same 3 same 4	US-PGPUB	OR	ON	2005/11/11 16:58
L8	166	2 same 3	US-PGPUB	OR	ON	2005/11/11 17:02
L9	411	(257/359 257/64 257/65 257/66 257/627 257/628.ccls.)	US-PGPUB	OR	ON	2005/11/11 16:59
L10	10	8 and 9	US-PGPUB	OR	ON	2005/11/11 16:59
L11	5228	(ge germanium)near11 (impurit\$3 low\$4 trace\$2)	USPAT	OR	ON	2005/11/11 16:59
L12	1059	(ge germanium)near11 (("10" "1" "5" "3" "4" "6" "7" "8" "9") adj2 (percent "%"))	USPAT	OR	ON	2005/11/11 17:00
L13	407310	(amorphous adj1 silicon ".alpha.si" a-si polysilicon polycrystalline microcrystalline silicon)	USPAT	OR	ON	2005/11/11 17:00
L14	518163	((("101" "{101}" "{101}" "[101]" "101")("001" "{001}" "{001}" "[001]" "001")("111" "{111}" "{111}" "[111]" "111") near21 (lattice plane orient\$6))	USPAT	OR	ON	2005/11/11 17:01
L15	1920	((amorphous adj1 silicon ".alpha.si" "a-si" polysilicon polycrystalline \$6crystalline silicon)near32 (lattice plane orient\$6))same (diffraction)	USPAT	OR	ON	2005/11/11 17:01
L16	4	2 same 3 same 5	US-PGPUB	OR	ON	2005/11/11 17:03
L17	32	11 same 13 same 14	USPAT	OR	ON	2005/11/11 17:06
L18	2	12 same 13 same 15	USPAT	OR	ON	2005/11/11 17:06
L19	2456	(ge germanium)near11 (impurit\$3 low\$4 trace\$2)	EPO; JPO; DERWENT	OR	ON	2005/11/11 17:06

L20	271	(ge germanium)near11 (("10" "1" "5" "3" "4" "6" "7" "8" "9") adj2 (percent "%"))	EPO; JPO; DERWENT	OR	ON	2005/11/11 17:13
L21	459940	(amorphous adj1 silicon ".alpha.si" a-si polysilicon polycrystalline microcrystalline silicon)	EPO; JPO; DERWENT	OR	ON	2005/11/11 17:07
L22	12043949	((("101" "{101}" "{101}" "[101]" "101")("001" "{001}" "{001}" "[001]" "001")("111" "{111}" "{111}" "[111]" "111") near21 (lattice plane orient\$6))	EPO; JPO; DERWENT	OR	ON	2005/11/11 17:07
L23	549	((amorphous adj1 silicon ".alpha.si" "a-si" polysilicon polycrystalline \$6crystalline silicon)near32 (lattice plane orient\$6))and (diffraction)	EPO; JPO; DERWENT	OR	ON	2005/11/11 17:12
L24	24	19 and 20	EPO; JPO; DERWENT	OR	ON	2005/11/11 17:12
L25	851	19 and 21	EPO; JPO; DERWENT	OR	ON	2005/11/11 17:12
L26	477	25 and 22	EPO; JPO; DERWENT	OR	ON	2005/11/11 17:11
L27	0	26 and 23	EPO; JPO; DERWENT	OR	ON	2005/11/11 17:12
L28	0	19 and 21 and 23	EPO; JPO; DERWENT	OR	ON	2005/11/11 17:12
L29	0	19 and 23	EPO; JPO; DERWENT	OR	ON	2005/11/11 17:12
L30	958	((amorphous adj1 silicon ".alpha.si" "a-si" polysilicon polycrystalline \$6crystalline silicon)and (lattice plane orient\$6))and (diffraction)	EPO; JPO; DERWENT	OR	ON	2005/11/11 17:12
L31	0	19 and 30	EPO; JPO; DERWENT	OR	ON	2005/11/11 17:13
L32	459	21 and 30	EPO; JPO; DERWENT	OR	ON	2005/11/11 17:13
L33	6	(thin adj film adj transistor\$2 tft). ti. and 32	EPO; JPO; DERWENT	OR	ON	2005/11/11 17:15
L34	19	(thin adj film adj transistor\$2 tft) and 32	EPO; JPO; DERWENT	OR	ON	2005/11/11 17:15
L35	13	34 not 33	EPO; JPO; DERWENT	OR	ON	2005/11/11 17:15